(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Condi	tions	Min	Max	Units
OFF CHAI	RACTERISTICS					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA, I _B = 0	846A / B 847A / B	65 45		V
V _{(BR)CES}	Collector-Base Breakdown Voltage	$I_C = 10 \ \mu A, \ I_E = 0$	846A / B 847A / B	80 50		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$		6.0		V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}$ $V_{CB} = 30 \text{ V}, T_A = 15$	60°C		15 5.0	nA μA

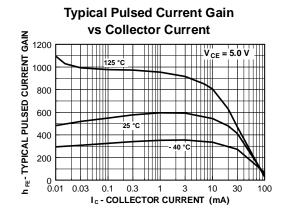
ON CHARACTERISTICS

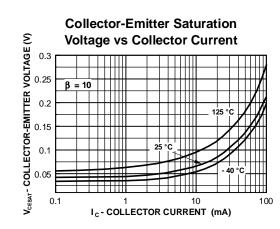
h _{FE}	DC Current Gain	$I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$			
		846A / 847A	110	220	
		846B / 847B	200	450	
		847C	420	800	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		0.25	V
		$I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$		0.6	V
V _{BE(on)}	Base-Emitter On Voltage	$I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	0.58	0.70	V
(-)	_	$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$		0.77	V

SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 5.0,$ f = 100 MHz	100		MHz
C _{obo}	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz		4.5	pF
NF	Noise Figure	$I_C = 0.2 \text{ mA}, V_{CE} = 5.0,$ $R_S = 2.0 \text{ k}\Omega, f = 1.0 \text{ kHz},$ BW = 200 Hz		10	dB

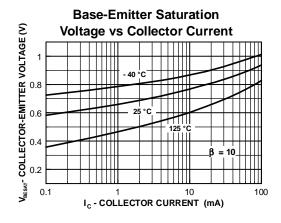
Typical Characteristics

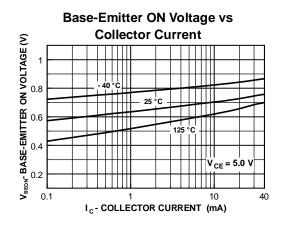




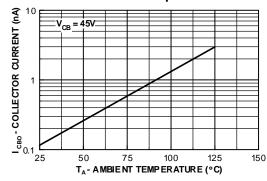
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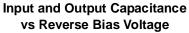
Typical Characteristics

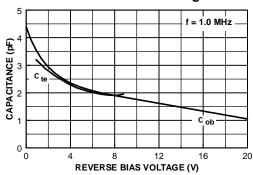




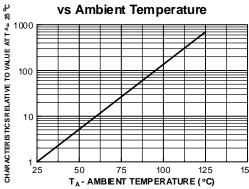
Collector-Cutoff Current vs Ambient Temperature



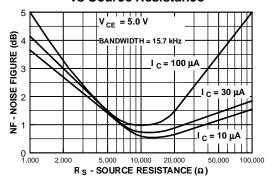




Normalized Collector-Cutoff Current vs Ambient Temperature

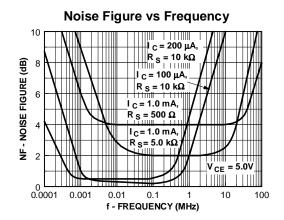


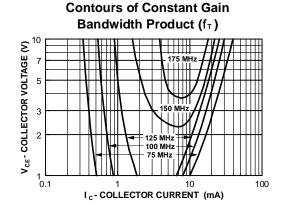
Wideband Noise Frequency vs Source Resistance

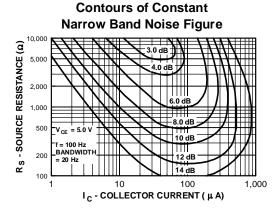


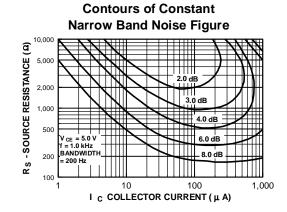
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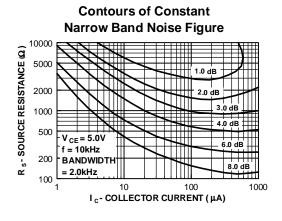
Typical Characteristics (continued)

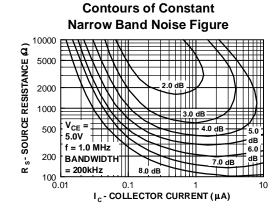








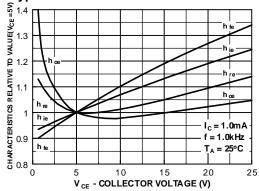




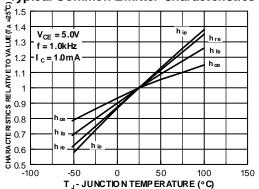
(continued)

Typical Common Emitter Characteristics (f = 1.0 kHz)

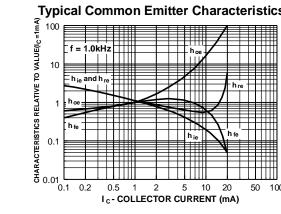
Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



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Rev. G